

HMC738LP4 / 738LP4E

v02.0309



MMIC VCO w/ HALF FREQUENCY OUTPUT & DIVIDE-BY-16, 20.9 - 23.9 GHz

Typical Applications

The HMC738LP4(E) is ideal for:

- Point-to-Point Radios
- Point-to-Multi-Point Radios / LMDS
- VSAT

Features

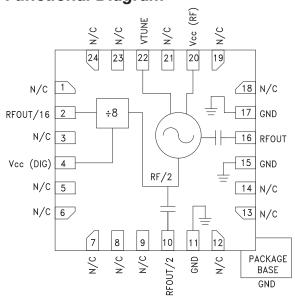
Pout: +9 dBm

Phase Noise: -95 dBc/Hz @ 100 kHz Typ.

No External Resonator Needed

24 Lead 4x4mm SMT Package: 16mm²

Functional Diagram



General Description

The HMC738LP4(E) is a GaAs InGaP Heterojunction Bipolar Transistor (HBT) MMIC VCO. The HMC738LP4(E) integrates a resonator, negative resistance device, varactor diode and divide-by-16 prescaler. The VCO's phase noise performance is excellent over temperature, shock, and process due to the oscillator's monolithic structure. Power output is +9 dBm typical from a 5V supply voltage. The voltage controlled oscillator is packaged in a low cost leadless QFN 4x4 mm surface mount package

Electrical Specifications, $T_A = +25^{\circ}$ C, Vcc (RF), Vcc (DIG) = +5V

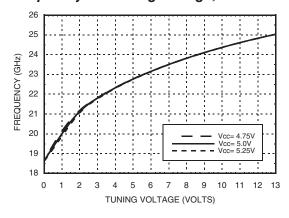
Parameter		Min.	Тур.	Max.	Units
Frequency Range	Fo Fo/2		20.9 - 23.9		GHz
Power Output	RF OUT/ RF OUT/2 RF OUT/16	3 -3.5 -7		15 +3.5 -1	dBm dBm
SSB Phase Noise @ 100 kHz Offset, Vtune= +5V @ RF Output			-95		dBc/Hz
Tune Voltage	Vtune	1		13	V
Supply Current	Icc (RF), Icc (DIG)	160	200	220	mA
Tune Port Leakage Current (Vtune= 13V)				10	μA
Output Return Loss			3		dB
Harmonics/Subharmonics	1/2 3/2		-23 -40		dBc dBc
Pulling (into a 2.0:1 VSWR)			22		MHz pp
Pushing @ Vtune= 5V	-		-90		MHz/V
Frequency Drift Rate			3.5		MHz/°C



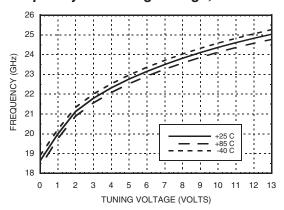


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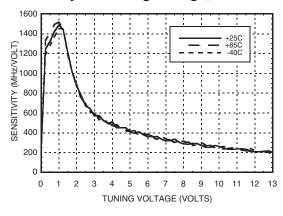
Frequency vs. Tuning Voltage, T= 25°C



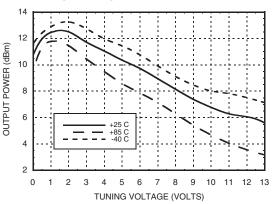
Frequency vs. Tuning Voltage, Vcc= +5V



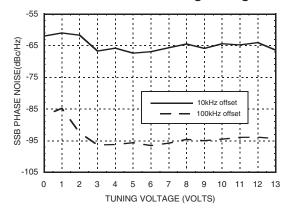
Sensitivity vs. Tuning Voltage, Vcc= +5V



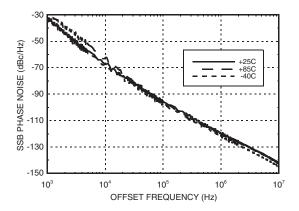
Output Power vs. Tuning Voltage, Vcc= +5V



SSB Phase Noise vs. Tuning Voltage



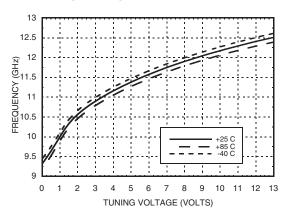
SSB Phase Noise @ Vtune= 5V



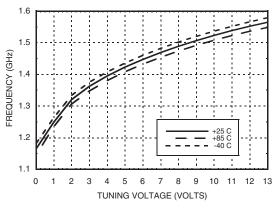




RFOUT/2 Frequency vs. Tuning Voltage, Vcc= +5V



Divide-by-16 Frequency vs. Tuning Voltage, Vcc= +5V

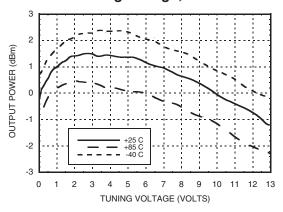


Absolute Maximum Ratings

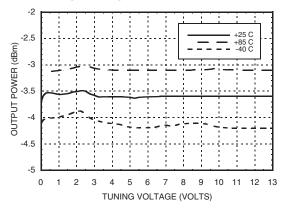
Vcc (RF), Vcc (DIG)	+5.5V
Vtune	0 to +15V
Junction Temperature	135° C
Continuous Pdiss (T= 85 °C) (derate 23 mW/° above 85 °C)	1.2 W
Thermal Resistance (junction to ground paddle)	43 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C

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RFOUT/2 Output Power Power vs. Tuning Voltage, Vcc= +5V



Divide-by-16 Output Power vs. Tuning Voltage, Vcc= +5V



Typical Supply Current vs. Vcc

Vcc (V)	Icc (mA)
4.75	175
5.0	200
5.25	220

Note: VCO will operate over full voltage range shown above.



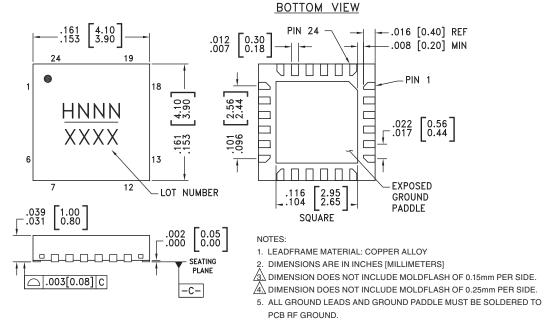
ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS





MMIC VCO w/ HALF FREQUENCY OUTPUT & DIVIDE-BY-16, 20.9 - 23.9 GHz

Outline Drawing



Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [3]
HMC738LP4	HMC738LP4 Low Stress Injection Molded Plastic		MSL1 [1]	H738 XXXX
HMC738LP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 [2]	<u>H738</u> XXXX

- [1] Max peak reflow temperature of 235 °C
- [2] Max peak reflow temperature of 260 °C
- [3] 4-Digit lot number XXXX

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 3, 5, 6, 7, 8, 9, 12, 13, 14, 18, 19, 21, 23, 24	N/C	No Connection required. These pins may be connected to RF/DC ground without affecting performance.	
2	RFOUT/16	RF/16 Divided Output. Requires DC Block.	5V ORFOUT/16
4	Vcc (DIG)	Supply voltage for prescaler. Can be omitted if prescaler is not needed to conserve approximately 100 mA.	(DIG) = 9pF





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Pin Descriptions (Continued)

Pin Number	Function	Description	Interface Schematic	
10	RFOUT/2	Half frequency output (AC coupled)	PORFOUT/2	
11, 15, 17	GND	Package bottom has an exposed metal paddle that must be RF & DC grounded.	GND =	
16	RFOUT	RF output (AC coupled).	RFOUT	
20	Vcc (RF)	Supply Voltage	Veco (RF) 34pF	
22	VTUNE	Control Voltage Input. Modulation port bandwidth dependent on drive source impedance.	1.5nH 250Ω VTUNE 0 4.0pF 3.8pF	

Typical Application Circuit

